



## 2A DDR TERMINATION REGULATOR

**AP2302L**

### General Description

The AP2302L linear regulator is designed to meet the JEDEC specification SSTL-2 and SSTL-18 for termination of DDR-SDRAM. The regulator can sink or source up to 2A current continuously, providing enough current for most DDR applications.  $V_{OUT}$  is designed to track the  $V_{REF}$  voltage within a  $\pm 20\text{mV}$  tolerance over the entire current range while preventing shooting through on the output stage. On-chip thermal limiting provides protection against a combination of high current and ambient temperature which would create an excessive junction temperature.

The AP2302L, used in conjunction with series termination resistors, provides an excellent voltage source for active termination schemes of high speed transmission lines as those seen in high speed memory buses and distributed backplane designs.

The AP2302L is available in SOIC-8 and TO-252-5 packages.

### Features

- Support Both DDR I ( $1.25V_{TT}$ ) and DDR II ( $0.9V_{TT}$ ) Requirements
- Source and Sink Current up to 2A
- High Accuracy Output Voltage at Full-load
- Adjustable  $V_{OUT}$  by External Resistors
- Shutdown for Standby or Suspend Mode Operation with High-impedance Output

### Applications

- DDR-SDRAM Termination
- DDR-II Termination
- SSTL-2 Termination

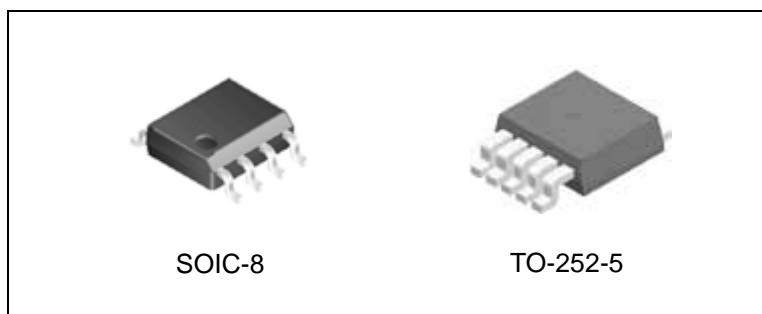


Figure 1. Package Types of AP2302L



## 2A DDR TERMINATION REGULATOR

AP2302L

## Pin Configuration

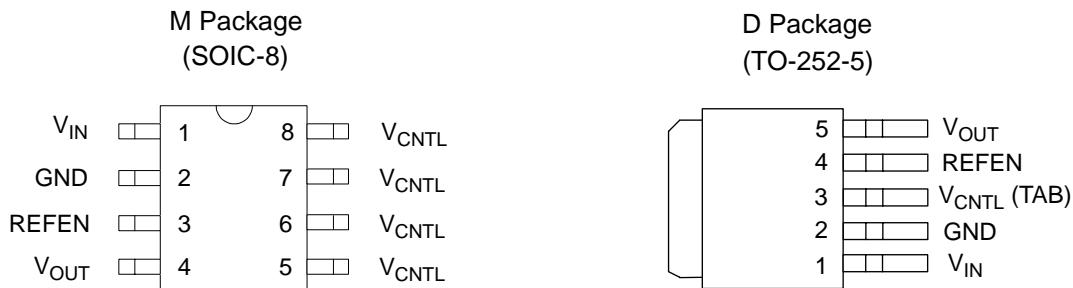


Figure 2. Pin Configuration of AP2302L (Top View)

## Pin Description

Pin Number		Pin Name	Function
SOIC-8	TO-252-5		
1	1	V <sub>IN</sub>	Power Input.
2	2	GND	Ground.
3	4	REFEN	Reference Voltage Input and Chip Enable.
4	5	V <sub>OUT</sub>	Output Voltage.
5, 6, 7, 8	3	V <sub>CNTL</sub>	Supply Voltage for Internal Circuit (Internally Connected for SOIC-8), (TAB for TO-252-5).



## 2A DDR TERMINATION REGULATOR

AP2302L

## Functional Block Diagram

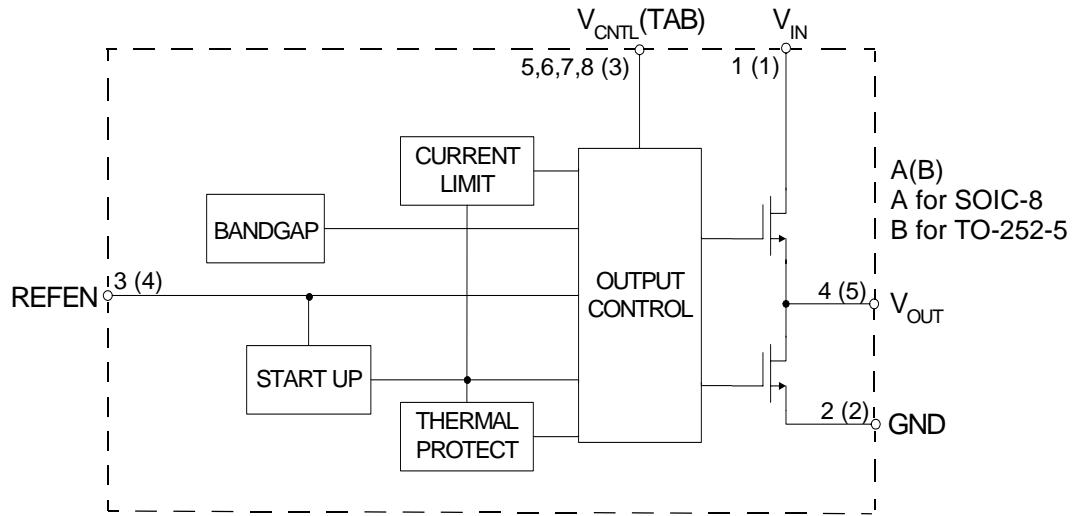
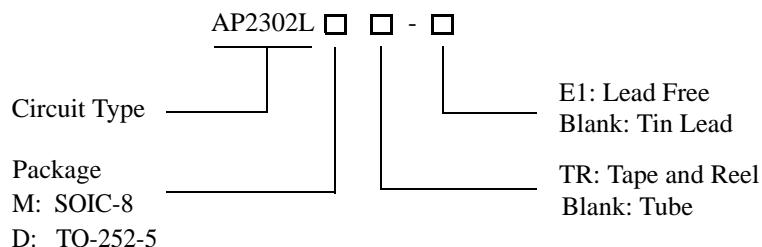


Figure 3. Functional Block Diagram of AP2302L

## Ordering Information



Package	Temperature Range	Part Number		Marking ID		Packing Type
		Tin Lead	Lead Free	Tin Lead	Lead Free	
SOIC-8	0 to 125°C		AP2302LM-E1		2302LM-E1	Tube
			AP2302LMTR-E1		2302LM-E1	Tape & Reel
TO-252-5	0 to 125°C		AP2302LD-E1		AP2302LD-E1	Tube
			AP2302LDTR-E1		AP2302LD-E1	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.



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AP2302L

## Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit
Supply Voltage for Internal Circuit	V <sub>CNTL</sub>	7		V
Power Dissipation	P <sub>D</sub>	Internally Limited		W
ESD (Human Body Model)	ESD	2		kV
Storage Temperature Range	T <sub>STG</sub>	-65 to 150		°C
Lead Temperature (Soldering, 5sec)	T <sub>LEAD</sub>	260		°C
Package Thermal Resistance (Free Air)	θ <sub>JC</sub>	SOIC-8	28	°C/W
		TO-252-5	13	

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

## Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage for Internal Circuit	V <sub>CNTL</sub> (Note 2, 3)		3.3	6	V
Power Input	DDR I DDR II	V <sub>IN</sub>	1.6	2.5	V <sub>CNTL</sub>
				1.8	
Junction Temperature	T <sub>J</sub>	0		125	°C

Note 2: Keep V<sub>CNTL</sub>  $\geqslant$  V<sub>IN</sub> in operation power on and power off sequences.

Note 3: For safe operation, V<sub>CNTL</sub> MUST be tied to 3.3V rather than 5V.



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AP2302L

## Electrical Characteristics

(T<sub>A</sub>=25°C, V<sub>IN</sub>=2.5V, V<sub>CNTL</sub>=3.3V, V<sub>REFEN</sub>=1.25V, C<sub>OUT</sub>=10μF (Ceramic), unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Output Offset Voltage	V <sub>OS</sub>	I <sub>L</sub> =0A (Note 4)	-20	0	20	mV	
Load Regulation	DDR I	I <sub>L</sub> =0 to 2A	-20	0	20	mV	
		I <sub>L</sub> =0 to -2A					
	DDR II	I <sub>L</sub> =0 to 2A	-20	0	20		
		I <sub>L</sub> =0 to -2A					
Quiescent Current of V <sub>CNTL</sub>	I <sub>Q</sub>	No Load		3	5	mA	
Leakage Current in Shutdown Mode	I <sub>SHDN</sub>	V <sub>REFEN</sub> <0.2V, R <sub>L</sub> =180Ω		3	6	μA	
<b>Protection</b>							
Current Limit	I <sub>LIMIT</sub>		2.6			A	
Thermal Shutdown Temperature	T <sub>SHDN</sub>	3.3V ≤ V <sub>CNTL</sub> ≤ 5V		150		°C	
Thermal Shutdown Hysteresis				50		°C	
<b>Shutdown Function</b>							
Shutdown Threshold Trigger		Output=High	0.8			V	
		Output=Low			0.2		

Note 4: V<sub>OS</sub> is the voltage measurement defined as V<sub>OUT</sub> subtracted from V<sub>REFEN</sub>.



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## 2A DDR TERMINATION REGULATOR

AP2302L

### Typical Performance Characteristics

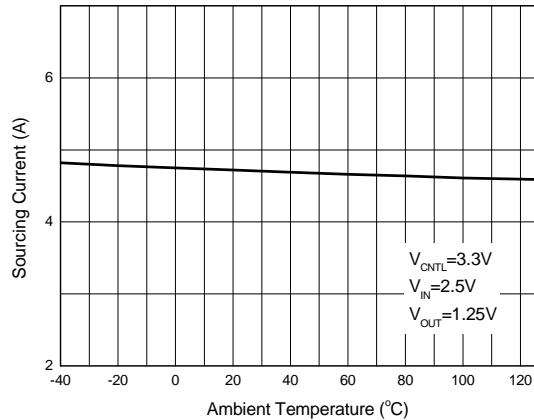


Figure 4. Sourcing Current vs. Ambient Temperature

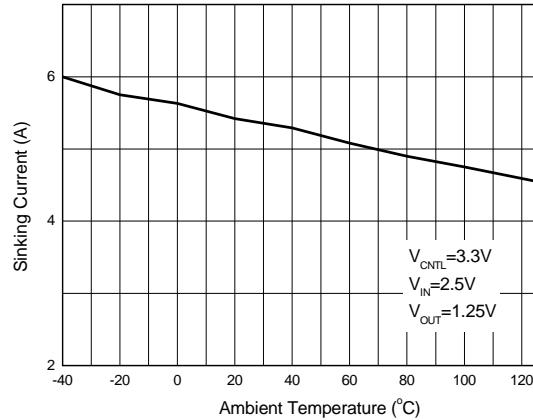


Figure 5. Sinking Current vs. Ambient Temperature

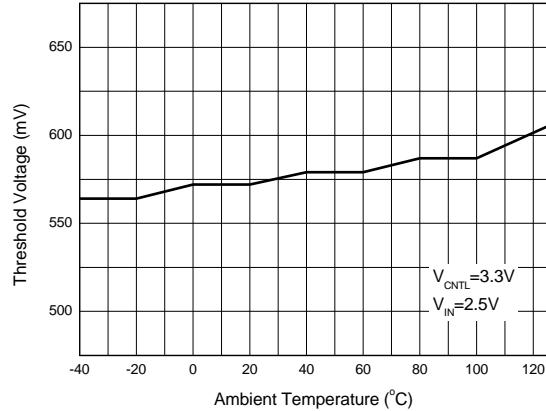


Figure 6. Threshold Voltage vs. Ambient Temperature

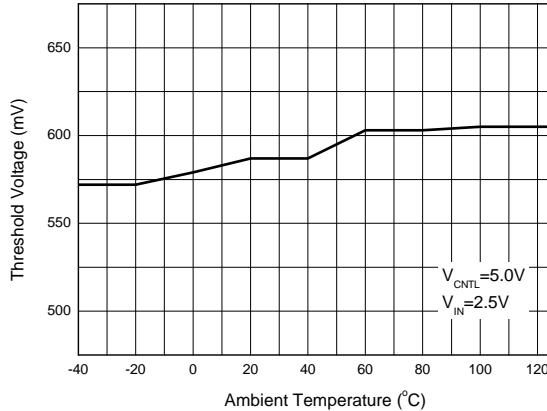


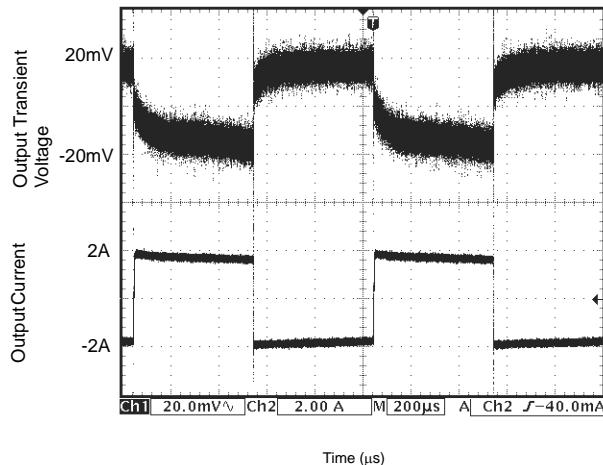
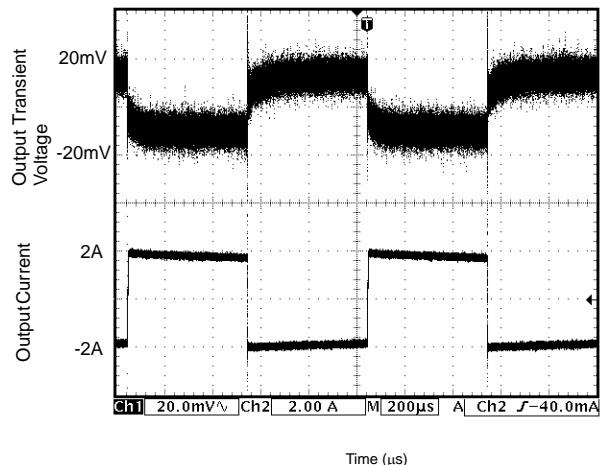
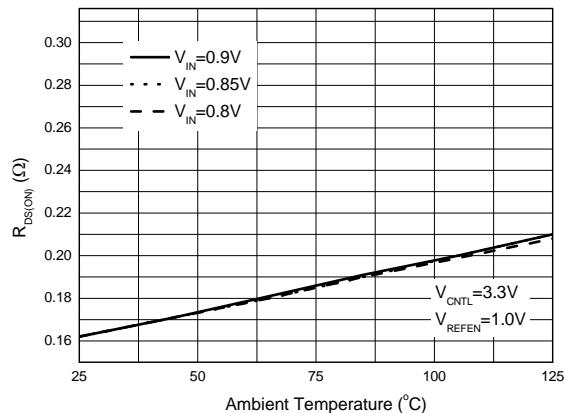
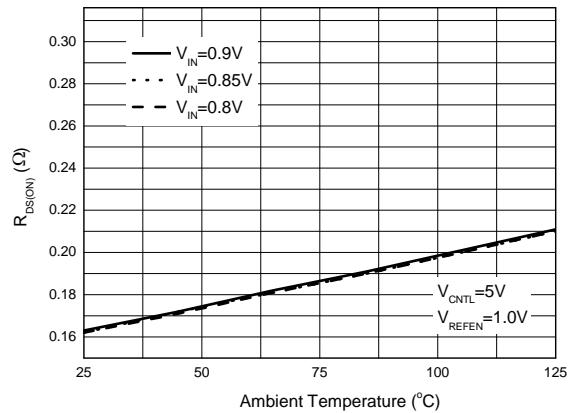
Figure 7. Threshold Voltage vs. Ambient Temperature



## 2A DDR TERMINATION REGULATOR

AP2302L

## Typical Performance Characteristics (Continued)

Figure 8. 0.9V<sub>TT</sub> at 2A Transient ResponseFigure 9. 1.25V<sub>TT</sub> at 2A Transient ResponseFigure 10.  $R_{DS(on)}$  vs. Ambient TemperatureFigure 11.  $R_{DS(on)}$  vs. Ambient Temperature



## 2A DDR TERMINATION REGULATOR

AP2302L

## Typical Performance Characteristics (Continued)

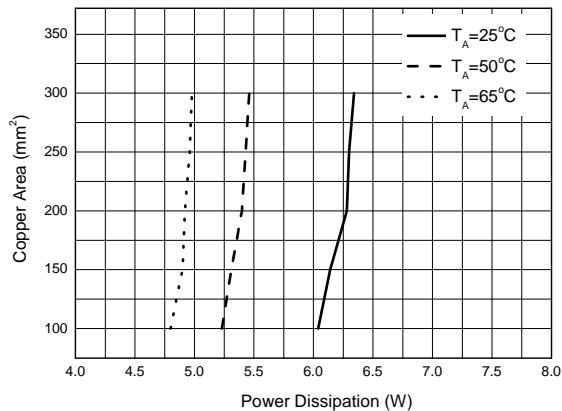


Figure 12. Copper Area vs. Power Dissipation  
(For SOIC-8)

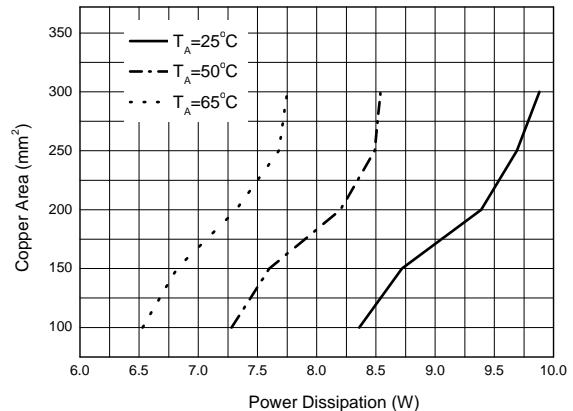


Figure 13. Copper Area vs. Power Dissipation  
(For TO-252-5)



## 2A DDR TERMINATION REGULATOR

AP2302L

## Typical Application

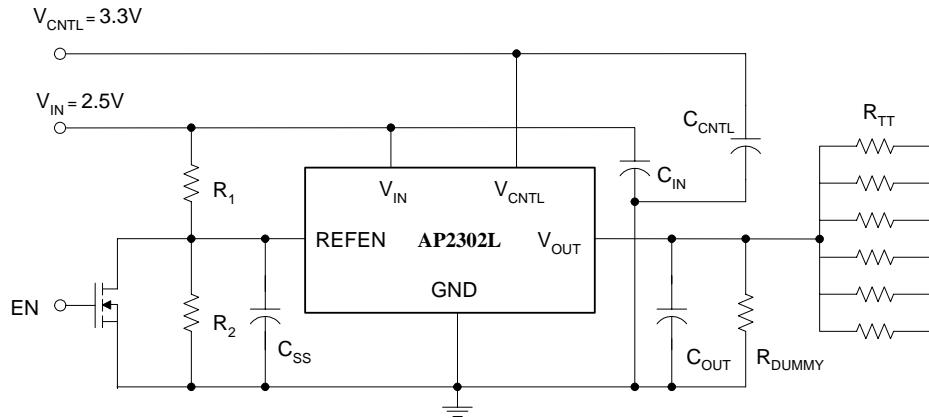


Figure 14. Typical Application of AP2302L

 $R_1 = R_2 = 100\text{K}\Omega$ ,  $R_{TT} = 50\Omega / 33\Omega / 25\Omega$  $R_{DUMMY} = 1\text{K}\Omega$ , as for  $V_{OUT}$  discharge when  $V_{IN}$  is not present but  $V_{CNTL}$  is present $C_{SS} = 1\mu\text{F}$ ,  $C_{IN} = 470\mu\text{F}$ ,  $C_{CNTL} = 47\mu\text{F}$ ,  $C_{OUT} = 470\mu\text{F}$



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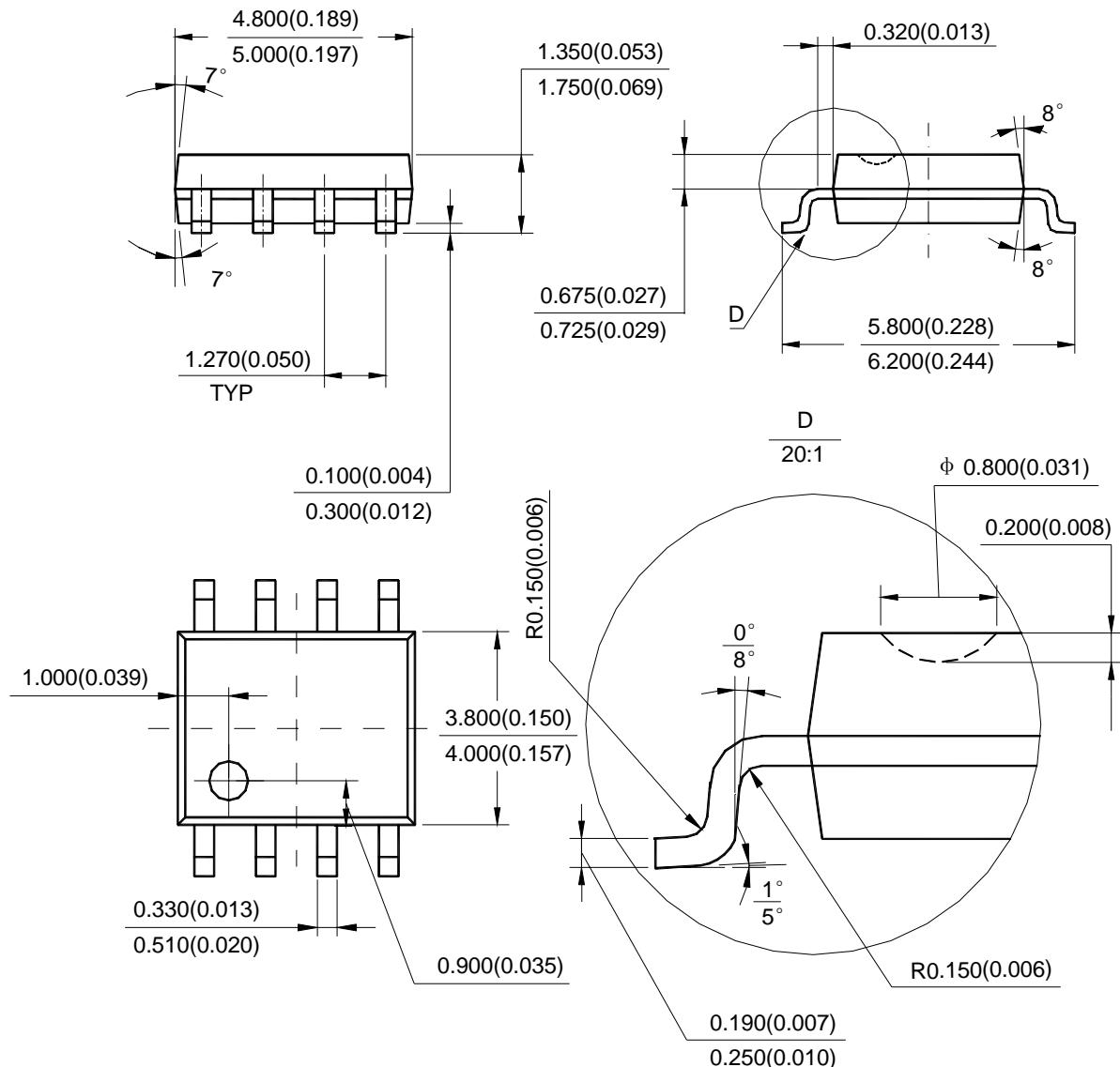
## 2A DDR TERMINATION REGULATOR

AP2302L

### Mechanical Dimensions

SOIC-8

Unit: mm(inch)





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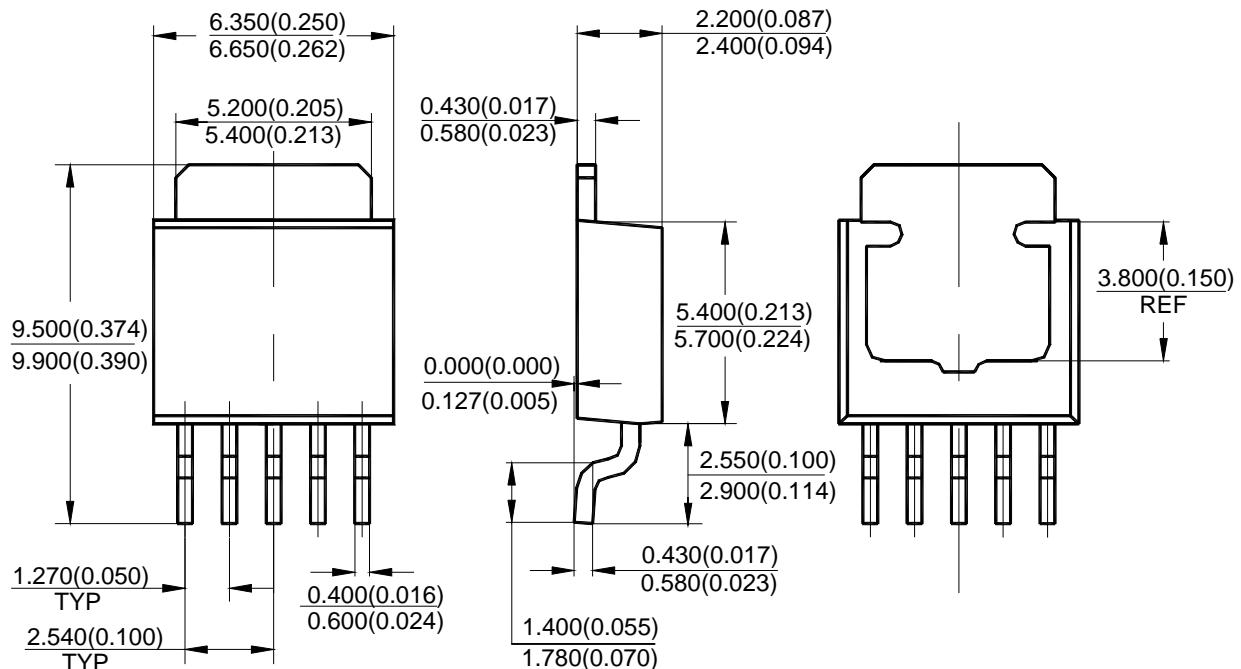
## 2A DDR TERMINATION REGULATOR

AP2302L

### Mechanical Dimensions (Continued)

TO-252-5

Unit: mm(inch)





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